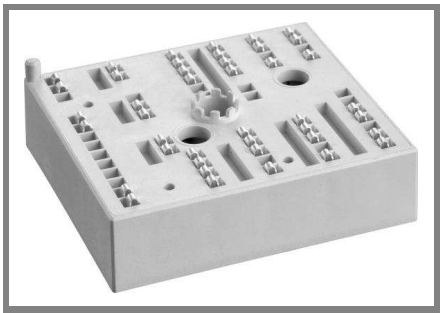
SKiiP 22NAB126V10



MiniSKiiP® 2

3-phase bridge rectifier + brake chopper + 3-phase bridge inverter

SKiiP 22NAB126V10

Features

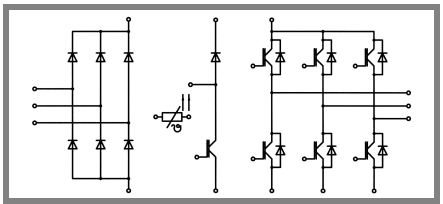
- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

- Inverter up to 10 kVA
- Typical motor power 5,5 kW

Remarks

- V_{CEsat} , V_F = chip level value



NAB

Absolute Maximum Ratings	T_s = 25 °C, unless otherwise specified		
Symbol	**Conditions**	**Values**	**Units**
IGBT - Inverter, Chopper			
V_{CES}		1200	V
I_C	T_s = 25 (70) °C	28 (22)	A
I_{CRM}		30	A
V_{GES}		± 20	V
T_j		- 40 ... + 150	°C
Diode - Inverter, Chopper			
I_F	T_s = 25 (70) °C	26 (20)	A
I_{FRM}		30	A
T_j		- 40 ... + 150	°C
Diode - Rectifier			
V_{RRM}		1600	V
I_F	T_s = 70 °C	61	A
I_{FSM}	t_p = 10 ms, sin 180 °, T_j = 25 °C	700	A
i^2t	t_p = 10 ms, sin 180 °, T_j = 25 °C	2400	A^2s
T_j		- 40 ... + 150	°C
Module			
I_{tRMS}	per power terminal (20 A / spring)	40	A
T_{stg}		- 40 ... + 125	°C
V_{isol}	AC, 1 min.	2500	V

Characteristics	T_s = 25 °C, unless otherwise specified				
Symbol	**Conditions**	**min.**	**typ.**	**max.**	**Units**
IGBT - Inverter, Chopper					
V_{CEsat}	I_{Cnom} = 15 A, T_j = 25 (125) °C		1,7 (2)	2,1 (2,4)	V
$V_{GE(th)}$	V_{GE} = V_{CE}, I_C = 0,6 mA	5	5,8	6,5	V
$V_{CE(TO)}$	T_j = 25 (125) °C		1 (0,9)	1,2 (1,1)	V
r_T	T_j = 25 (125) °C		47 (73)	60 (87)	mΩ
C_{ies}	V_{CE} = 25 V, V_{GE} = 0 V, f = 1 MHz		1		nF
C_{oes}	V_{CE} = 25 V, V_{GE} = 0 V, f = 1 MHz		0,1		nF
C_{res}	V_{CE} = 25 V, V_{GE} = 0 V, f = 1 MHz		0,1		nF
$R_{th(j-s)}$	per IGBT		1,15		K/W
$t_{d(on)}$	under following conditions		25		ns
t_r	V_{CC} = 600 V, V_{GE} = ± 15 V		25		ns
$t_{d(off)}$	I_{Cnom} = 15 A, T_j = 125°C		385		ns
t_f	R_{Gon} = R_{Goff} = 30 Ω		90		ns
E_{on}	inductive load		2		mJ
E_{off}			1,9		mJ
Diode - Inverter, Chopper					
V_F = V_{EC}	I_{Fnom} = 15 A, T_j = 25 (125) °C		1,6 (1,6)	1,8 (1,8)	V
$V_{(TO)}$	T_j = 25 (125) °C		1 (0,8)	1,1 (0,9)	V
r_T	T_j = 25 (125) °C		40 (53)	47 (60)	mΩ
$R_{th(j-s)}$	per diode		1,95		K/W
I_{RRM}	under following conditions		25		A
Q_{rr}	I_{Fnom} = 15 A, V_R = 600 V		3		µC
E_{rr}	V_{GE} = 0 V, T_j = 125 °C		1,1		mJ
	di_F/dt = 900 A/µs				
Diode - Rectifier					
V_F	I_{Fnom} = 35 A, T_j = 25 °C		1,1		V
$V_{(TO)}$	T_j = 150 °C		0,8		V
r_T	T_j = 150 °C		11		mΩ
$R_{th(j-s)}$	per diode		0,9		K/W
Temperature Sensor					
R_{ts}	3 %, T_r = 25 (100) °C		1000(1670)		Ω
Mechanical Data					
w			95		g
M_s	Mounting torque	2		2,5	Nm

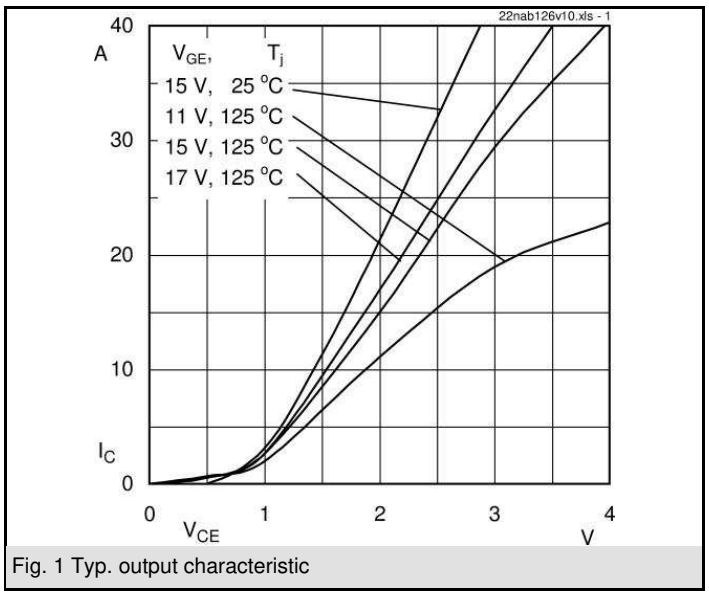


Fig. 1 Typ. output characteristic

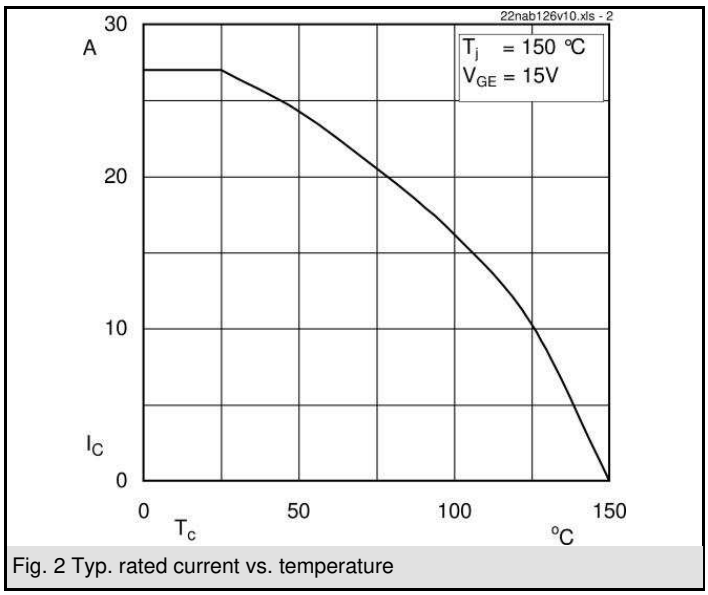


Fig. 2 Typ. rated current vs. temperature

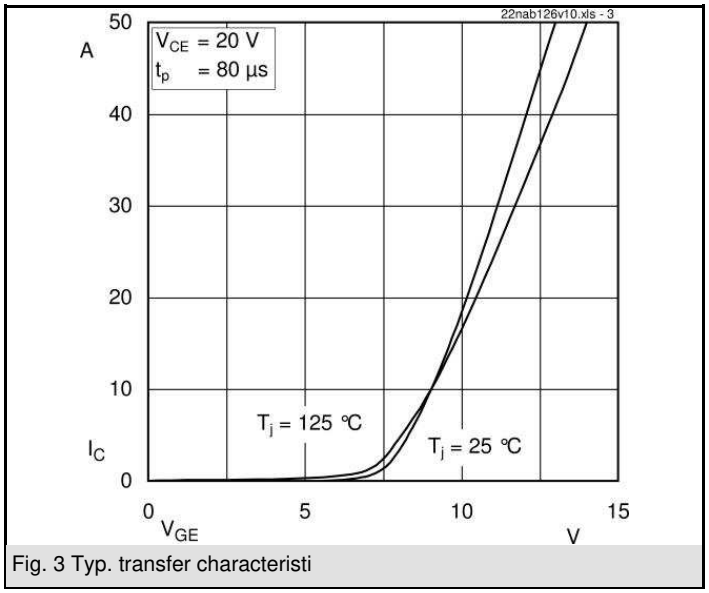


Fig. 3 Typ. transfer characteristi

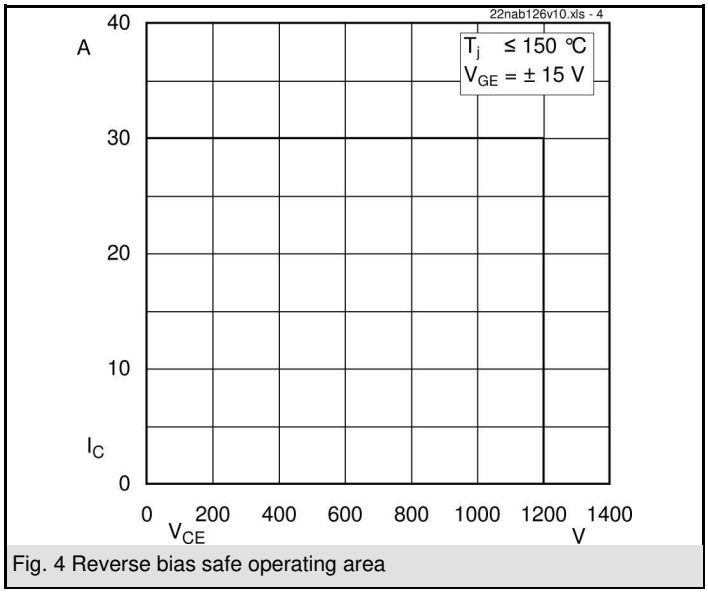


Fig. 4 Reverse bias safe operating area

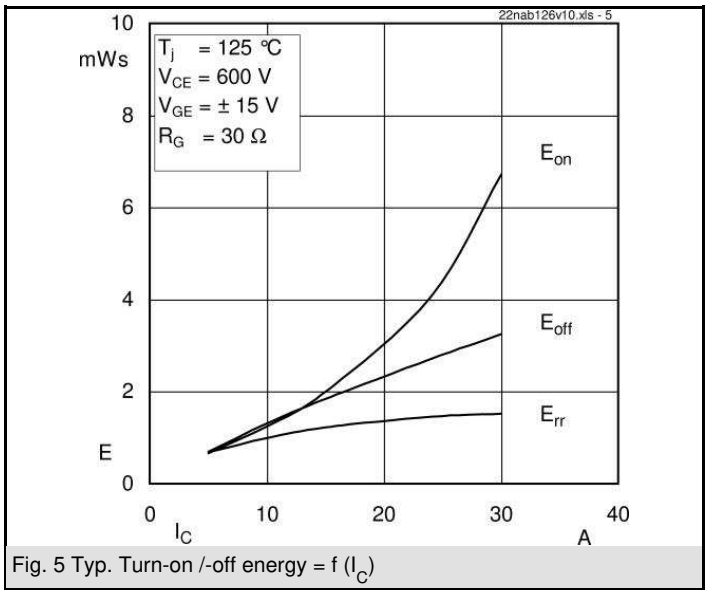


Fig. 5 Typ. Turn-on /-off energy = f (I_C)

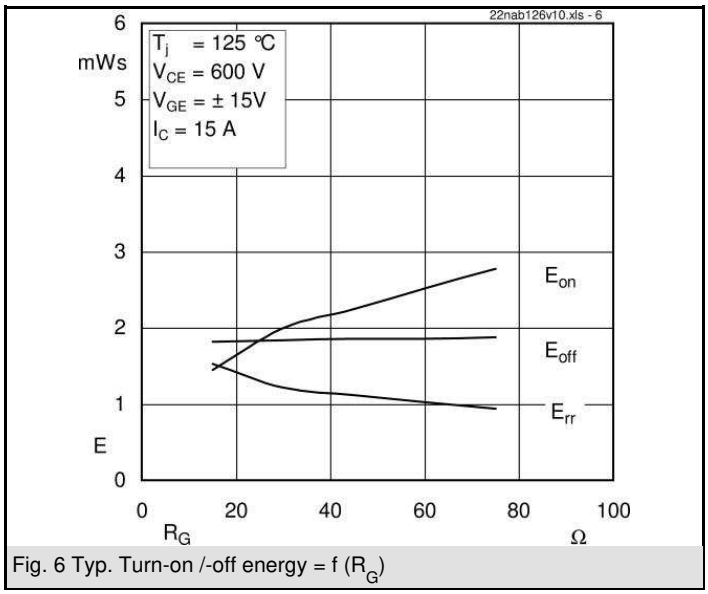


Fig. 6 Typ. Turn-on /-off energy = f (R_G)

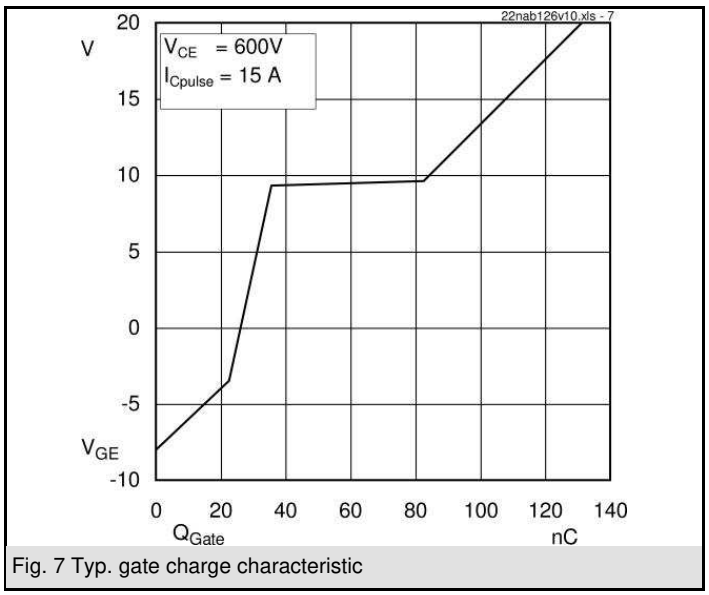


Fig. 7 Typ. gate charge characteristic

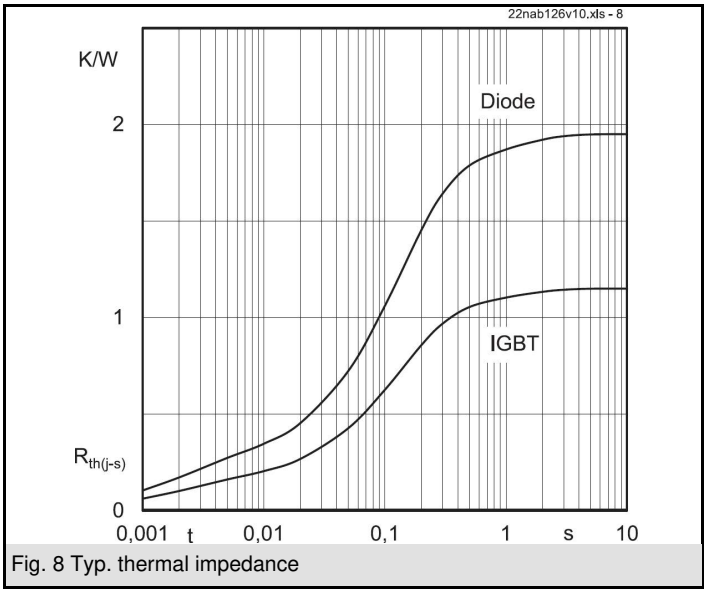


Fig. 8 Typ. thermal impedance

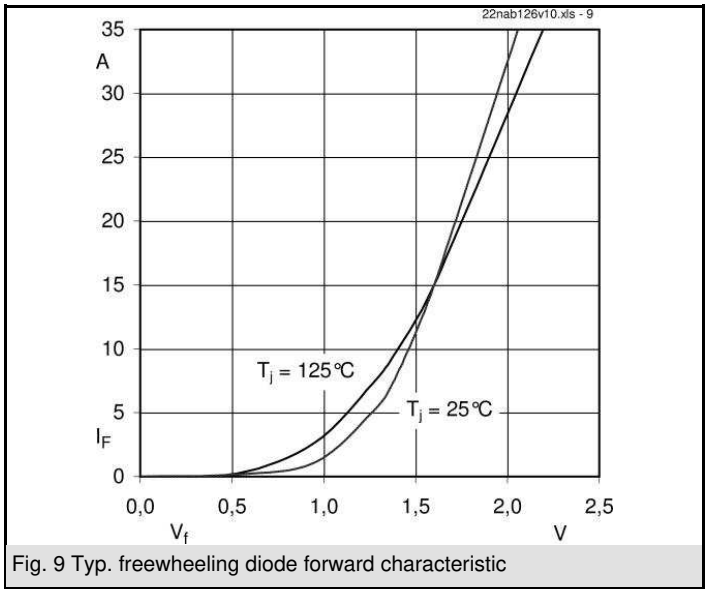


Fig. 9 Typ. freewheeling diode forward characteristic

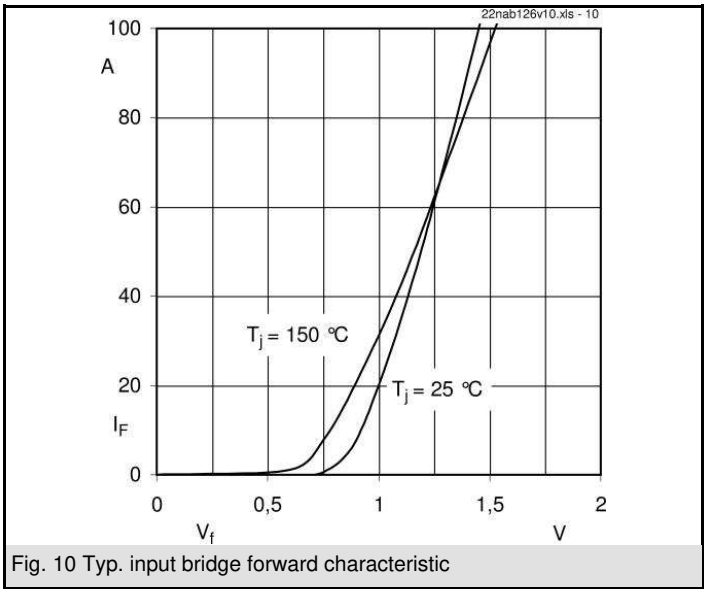
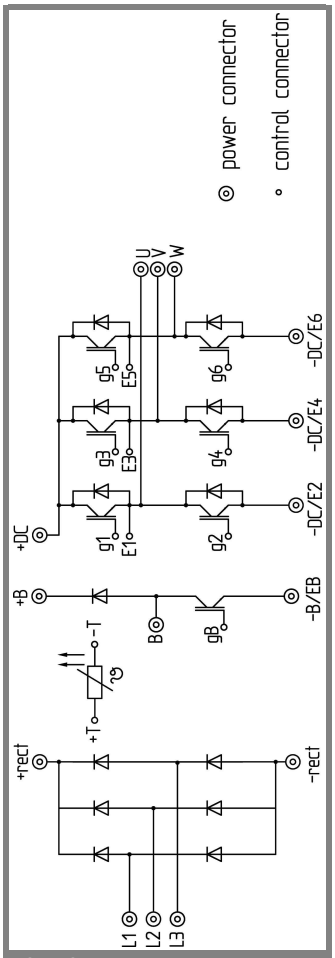
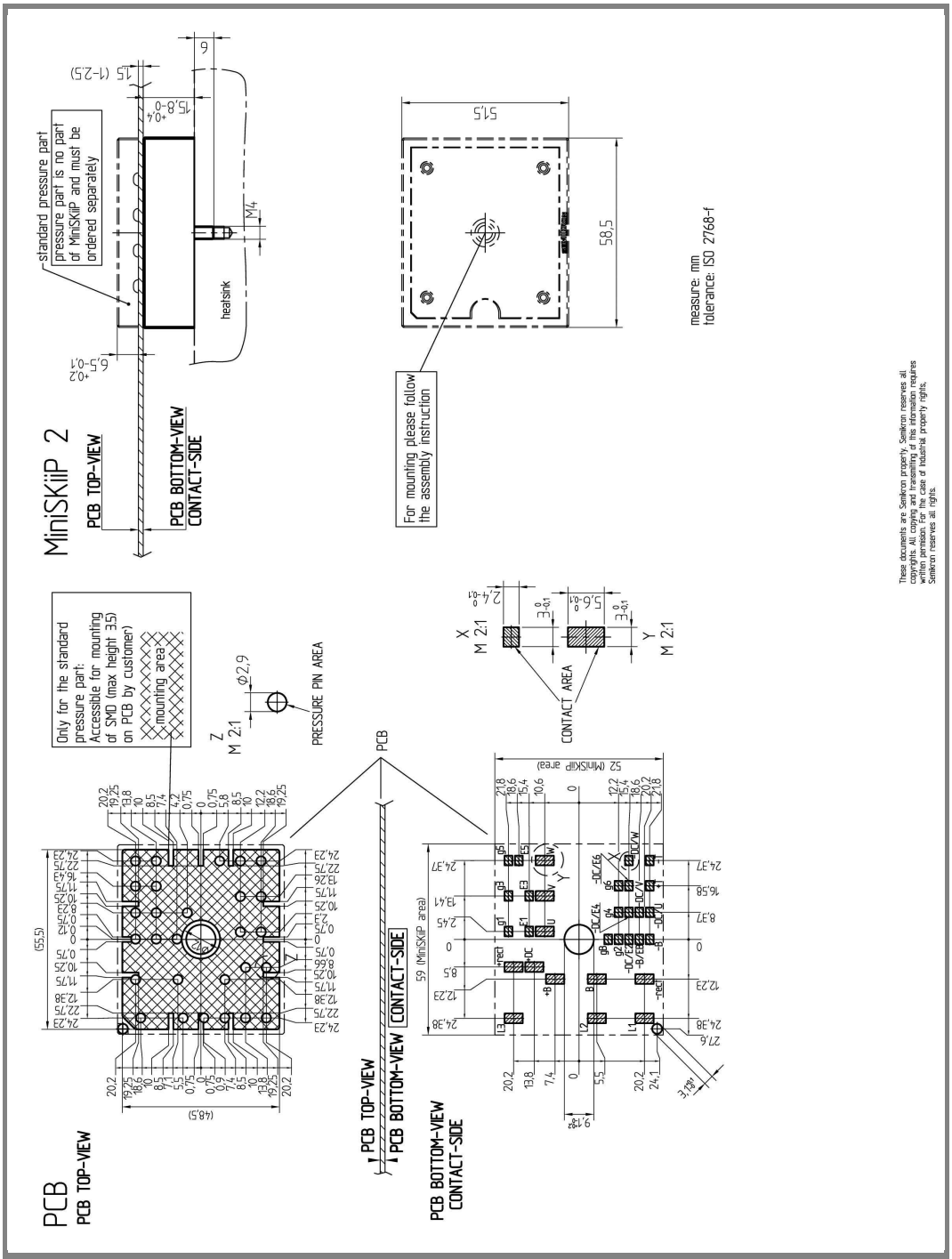


Fig. 10 Typ. input bridge forward characteristic



circuit



pinout, dimensions

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

***IMPORTANT INFORMATION AND WARNINGS**

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